NSN 5961-01-298-7956

No Fiig: A110a0



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-298-7956 **Inclosure Material:** Metal **Overall Length:** Between 1.172 inches and 1.453 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.669 inches and 0.688 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 54.0 repetitive peak reverse voltage and 60.0 nonrepetitive peak reverse voltage and 45.0 working peak reverse voltage and 45.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 75.00 amperes forward current, average absolute and 1000.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 53711-5616481 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**